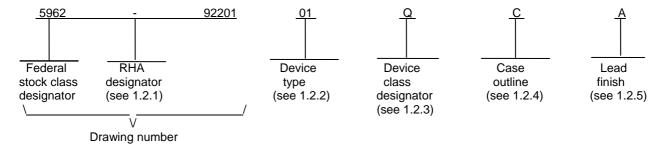
								F	REVIS	IONS										
LTR	DESCRIPTION								DA	TE (YI	R-MO-	DA)		APPR	OVED					
А	Correct I_{OL} for V_{CC} = 3.0 V dc and 3.6 V dc in section CAGE F8859. Add case outline X. Add device type 0 delta limits. Update the boilerplate to remove classes and to reflect the changes in accordance with MIL-PR requirements. Editorial changes throughout - jak					02. Ac s B and	ld tabl l S crit	e III,	03-04-17 Thomas M. I			. Hess								
В	Upd	ate bo	ilerpla	te to c	urrent	requir	ement	s of M	IIL-PR	F-385	35 ja	ak		10-0	4-01		Tho	mas M	. Hess	
REV																				
SHEET																				
REV	В	В	В	В																
SHEET	15	16	16	17			_		_		_	_	_	_			_			
REV STATUS OF SHEETS				RE\			В	В	В	В	B	В	B _	В	В	В	В	В	В	В
PMIC N/A				SHEET 1 2 3 PREPARED BY Larry T. Gauder CHECKED BY Thomas J. Ricciuti				3	4 5 6 7 8 9 10 11 12 13 14 DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 http://www.dscc.dla.mil						14					
STAI MICRO DRA		CUIT																		
AVA	THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE			APF	_	ED BY nica L	Poelk	ing		PAF	MICROCIRCUIT, DIGITAL, ADVANCED CMOS, NINE- PARITY GENERATOR/CHECKER, MONOLITHIC			-BIT						
DEPAF AND AGEN			DRA	WING		ROVAL 6-03	_ DAT	E		CON										
AMS	SC N/A	Ą		REV	'ISION	I LEVE	EL B				ZE A		GE CC 6 726 8			5	962-	-9220)1	
										SHE	ET	<u> </u>	1	OF	17					

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1. SCOPE

- 1.1 <u>Scope</u>. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.
 - 1.2 PIN. The PIN is as shown in the following example:



- 1.2.1 <u>RHA designator</u>. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 <u>Device type(s)</u>. The device type(s) identify the circuit function as follows:

Device type	<u>Generic number</u>	<u>Circuit function</u>
01	54AC280	9-bit parity generator/checker
02	54AC280	9-bit parity generator/checker

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

<u>Device class</u> <u>Device requirements documentation</u>

M Vendor self-certification to the requirements for MIL-STD-883 compliant,

non-JAN class level B microcircuits in accordance with MIL-PRF-38535,

appendix A

Q or V Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
С	GDIP1-T14 or CDIP2-T14	14	Dual-in-line package
D	GDFP1-F14 or CDFP2-F14	14	Flat pack
Χ	CDFP3-F14	14	Flat pack
2	CQCC1-N20	20	Square leadless chip carrier

1.2.5 <u>Lead finish</u>. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

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1.3 Absolute maximum ratings. 1/2/3/

Supply voltage range (V _{CC})	
DC input voltage range (V _{IN})	0.5 V dc to V_{CC} + 0.5 V dc
DC output voltage range (V _{OUT})	0.5 V dc to V_{CC} + 0.5 V dc
DC Input diode current (I_{IK}) (V_{IN} = -0.5 V and V_{CC} + 0.5 V)	±20 mA
DC Input diode current (I_{OK}) (V_{OUT} = -0.5 V and V_{CC} + 0.5 V)	±20 mA
DC output current (I _{OUT}) (per output pin)	±50 mA
DC V _{CC} or GND current (I _{CC} , I _{GND}) (per pin)	±100 mA
Storage temperature range (T _{STG})	65°C to +150°C
Maximum power dissipation (P _D)	500 mW
Lead temperature (soldering, 10 seconds)	+300°C
Thermal resistance, junction-to-case (θ_{JC})	See MIL-STD-1835
Junction temperature (T _J)	+175°C
Case operating temperature range (T _C)	

1.4 Recommended operating conditions. 2/3/4/

Supply voltage range (V _{CC}) Input voltage range (V _{IN}) Output voltage range (V _{OUT}) Maximum Low level input voltage (V _{II}):	. +0.0 V dc to V _{CC}
V _{CC} = 3.0 V dc	. 0.90 V dc 1.35 V dc
V _{CC} = 5.5 V dc	. 1.65 V dc
Minimum High level input voltage (V _{IH}): V _{CC} = 3.0 V dc	. 2.10 V dc
$V_{CC} = 4.5 \text{ V dc.}$ $V_{CC} = 5.5 \text{ V dc.}$. 3.15 V dc . 3.85 V dc
Case operating temperature range (T _C)	
Input edge rate ($\Delta V/\Delta t$) maximum (V_{IN} from 30% to 70% of V_{CC})	
V _{CC} = 3.0 V dc and 3.6 V dc	. +12 mA . +24 mA
Maximum high level output current (I _{OH}): V _{CC} = 3.0 V dc and 3.6 V dc	12 mA
V _{CC} = 4.5 V dc and 5.5 V dc	24 mA

- Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability. The maximum junction temperature may be exceeded for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.
- 2/ Unless otherwise noted, all voltages are referenced to GND.
- The limits for the parameters specified herein shall apply over the full specified V_{CC} range and case temperature range of -55°C to +125°C.
- $\underline{4}$ / Operation from 2.0 V dc to 3.0 V dc is provided for compatibility with data retention and battery back up systems. Data retention implies no input transitions and no stored data loss with the following conditions: V_{IH} ≥ 70 percent of V_{CC}, V_{IL} ≤ 30 percent of V_{CC}, V_{OH} ≥ 70 percent of V_{CC} at −20 μA, V_{OL} ≤ 30 percent of V_{CC} at 20 μA.

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2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solicitation.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at https://assist.daps.dla.mil/quicksearch/ or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia

2.2 <u>Non-Government publications</u>. The following documents form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents which are DoD adopted are those listed in the issue of the DoDISS cited in the solicitation. Unless otherwise specified, the issues of documents not listed in the DoDISS are the issues of the documents cited in the solicitation.

ELECTRONIC INDUSTRIES ALLIANCE (EIA)

EIA/JEDEC Standard No. 78 - IC Latch-Up Test

JEDEC Standard No. 20 - Standard for Description of 54/74ACXXXX and 54/74ACTXXXX Advanced High-Speed CMOS Devices

(Applications for copies should be addressed to the Electronics Industries Alliance, 2500 Wilson Boulevard, Arlington VA 22201-3834.)

(Non-Government standards and other publications are normally available from the organizations that prepare or distribute the documents. These documents may also be available in or through libraries or other informational services.)

2.3 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 <u>Item requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

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- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.
 - 3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein.
 - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.3 Truth table. The truth table shall be as specified on figure 2.
 - 3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3.
 - 3.2.5 Switching waveforms and test circuit. The switching waveforms and test circuit shall be as specified on figure 4.
- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.
- 3.5.1 <u>Certification/compliance mark</u>. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.
- 3.6 <u>Certificate of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change for device class M</u>. For device class M notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.
- 3.9 <u>Verification and review for device class M.</u> For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 39 (see MIL-PRF-38535, appendix A).

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Test and	Symbol	Test conditions 2/	Device	V _{CC}	Group A	Limit	s 4/	Unit
MIL-STD-883 test method <u>1</u> /	Oyin.oo.	$-55^{\circ}\text{C} \le T_{\text{C}} \le +125^{\circ}\text{C}$ $+3.0 \text{ V} \le V_{\text{CC}} \le +5.5 \text{ V}$	type <u>3</u> / and	*00	subgroups	L	.o <u>.</u> i,	
		unless otherwise specified	device class			Min	Max	
Positive input clamp voltage 3022	V _{IC+}	For input under test, I _{IN} = 1.0 mA	AII Q, V	0.0 V	1	0.4	1.5	V
Negative input clamp voltage 3022	V _{IC} -	For input under test, I _{IN} = -1.0 mA	AII Q, V	Open	1	-0.4	-1.5	V
High level output voltage 3006	V _{OH1}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 2.10 \text{ V}$ $V_{IL} = 0.90 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OH} = -50 \mu\text{A}$	All All	3.0 V	1, 2, 3	2.90		V
	V _{OH2}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.15 \text{ V}$ $V_{IL} = 1.35 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OH} = -50 \mu\text{A}$	All All	4.5 V		4.40		-
	Vонз	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.85 \text{ V}$ $V_{IL} = 1.65 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OH} = -50 \mu\text{A}$	All All	5.5 V		5.40		
	V _{ОН4}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 2.10 \text{ V}$ $V_{IL} = 0.90 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OH} = -4.0 \text{ mA}$	All All	3.0 V		2.40		
	V _{ОН5}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.15 \text{ V}$ $V_{IL} = 1.35 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OH} = -24 \text{ mA}$	All All	4.5 V		3.70		-
	V _{ОН6}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.85 \text{ V}$ $V_{IL} = 1.65 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OH} = -24 \text{ mA}$	All All	5.5 V	1, 2, 3	4.70		

See footnotes at end of table.

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Test and MIL-STD-883 test method 1/	Symbol	Test conditions $\underline{2}/$ -55°C \leq T _C \leq +125°C +3.0 V \leq V _{CC} \leq +5.5 V	Device type <u>3</u> / and	V _{CC}	Group A subgroups	Limit	s <u>4</u> /	Uni
		unless otherwise specified	device class			Min	Max	
ligh level output voltage 3006	V _{ОН7} <u>5</u> /	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.85 \text{ V}$ $V_{IL} = 1.65 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OH} = -50 \text{ mA}$	All All	5.5 V	1, 2, 3	3.85		V
Low level output voltage 3007	V _{OL1}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 2.10 \text{ V}$ $V_{IL} = 0.90 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OL} = 50 \mu\text{A}$	All All	3.0 V	1, 2, 3		0.1	
	V _{OL2}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.15 \text{ V}$ $V_{IL} = 1.35 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OL} = 50 \mu\text{A}$	AII AII	4.5 V	1, 2, 3		0.1	
	V _{OL3}	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.85 \text{ V}$ $V_{IL} = 1.65 \text{ V}$ For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OL} = 50 \mu\text{A}$	AII AII	5.5 V	1, 2, 3		0.1	
	V _{OL4}	For all inputs affecting output under test, V _{IN} = V _{IH} or V _{IL}	All Q, V	3.0 V	1, 3		0.4	- - -
		$V_{IH} = 2.10 \text{ V}$	Q, V		2		0.5	
		V _{IL} = 0.90 V For all other inputs,	All		1		0.4	
		$V_{IN} = V_{CC}$ or GND $I_{OL} = 12 \text{ mA}$	M		2, 3		0.5	
	V _{OL5}	For all inputs affecting output under	All	4.5 V	1, 3		0.4	
		test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.15 \text{ V}$	Q, V		2		0.5	
		V _{IL} = 1.35 V For all other inputs,	All		1		0.4	
		$V_{IN} = V_{CC}$ or GND $I_{OL} = 24$ mA	М		2, 3		0.5	
	V _{OL6}	For all inputs affecting output under	All	5.5 V	1, 3		0.4	
		test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.85 \text{ V}$	Q, V		2		0.5	
		V _{IL} = 1.65 V For all other inputs,	All M		1		0.4	
	V _{IN} =	$V_{IN} = V_{CC}$ or GND $I_{OL} = 24$ mA	IVI		2, 3		0.5	

See footnotes at end of table.

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		TABLE I. Electrical performance cl	haracterist	tics - Con	itinued.			
Test and MIL-STD-883 test method 1/	Symbol	Test conditions $\underline{2}/$ -55°C \leq T _C \leq +125°C +4.5 V \leq V _{CC} \leq +5.5 V	Device type and <u>3</u> /	V _{CC}	Group A subgroups	Limi	its <u>4</u> /	Unit
		unless otherwise specified	Device class			Min	Max	
Low level output voltage 3007	V _{OL7} <u>5</u> /	For all inputs affecting output under test, $V_{IN} = V_{IH}$ or V_{IL} $V_{IH} = 3.85$ V $V_{IL} = 1.65$ V For all other inputs, $V_{IN} = V_{CC}$ or GND $I_{OL} = 50$ mA	AII AII	5.5 V	1, 2, 3		1.65	V
Input leakage current high	I _{IH}	For input under test, $V_{IN} = V_{CC}$ For all other inputs, $V_{IN} = V_{CC}$ or GND	All Q, V	5.5 V	1 2	 	0.1 1.0	μА
3010			All	5.5 V	1		0.1	
			M	0.0 v	2, 3		1.0	
Input leakage current low	I _{IL}	For input under test, $V_{IN} = GND$ For all other inputs, $V_{IN} = V_{CC}$ or GND	AII Q, V	5.5 V	1 2	_	-0.1 -1.0	μΑ
3009			All M	5.5 V	1 2, 3		-0.1 -1.0	<u> </u>
Input capacitance 3012	C _{IN}	T _C = +25°C See 4.4.1c	AII AII	GND	4		10	pF
Power dissipation capacitance	C _{PD} <u>6</u> /	T _C = +25°C See 4.4.1c	AII AII	5.0 V	4		95	pF
Quiescent supply	I _{CCH}	For all inputs, $V_{IN} = V_{CC}$ or GND	All	5.5 V	1	_ 	2.0	μΑ
current, output high			Q, V	<u> </u>	2		40.0 8.0	_
3005			All M	5.5 V	2, 3		160.0	-
Quiescent supply	I _{CCL}	For all inputs, V _{IN} = V _{CC} or GND	All	5.5 V	1		2.0	μА
current, output	.002	1 01 0111111111111111111111111111111111	Q, V	0.0	2		40.0	μ
low 3005			All	5.5 V	1	 	8.0	
Latch-up input/output over-voltage	I _{CC} (O/V1) 7/	$\begin{split} t_w &\geq 100~\mu\text{s},~t_{cool} \geq t_w \\ 5~\mu\text{s} &\leq t_r \leq 5~\text{ms} \\ 5~\mu\text{s} &\leq t_f \leq 5~\text{ms} \\ V_{test} &= 6.0~V \\ V_{CCQ} &= 5.5~V \end{split}$	AII Q, V	5.5 V	2, 3		160.0 200	mA
Latch-up	I _{CC}	V _{over} = 10.5 V	All	5.5 V	2		200	mA
input/output positive over- current	(O/I1+)	$\begin{split} t_w &\geq 100 \mu \text{s, } t_{cool} \geq t_w \\ 5 \mu \text{s} \leq t_r \leq 5 m \text{s} \\ 5 \mu \text{s} \leq t_f \leq 5 m \text{s} \\ V_{test} &= 6.0 V \\ V_{CCQ} &= 5.5 V \\ I_{trigger} &= +120 m \text{A} \end{split}$	Q, V	3.3 V	2		200	IIIA

See footnotes at end of table.

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TABLE I. <u>Electrical performance characteristics</u> – Continued.								
Test and MIL-STD-883 test method 1/	Symbol	Test conditions $\underline{2}/$ -55°C \leq T _C \leq +125°C +4.5 V \leq V _{CC} \leq +5.5 V	Device type and 3/	V _{CC}	Group A subgroups	Limit Min	ts <u>4</u> / Max	Unit
test method <u>h</u>		unless otherwise specified	Device class			IVIIII	IVIAX	
Latch-up input/output negative over- current	I _{CC} (O/I1-)	$\begin{split} t_w & \geq 100~\mu\text{s}, t_{\text{cool}} \geq t_w \\ 5~\mu\text{s} \leq t_r \leq 5~m\text{s} \\ 5~\mu\text{s} \leq t_f \leq 5~m\text{s} \\ V_{\text{test}} = 6.0~V \\ V_{\text{CCQ}} = 5.5~V \\ I_{\text{trigger}} = -120~m\text{A} \end{split}$	AII Q, V	5.5 V	2		200	mA
Latch-up supply over-voltage	Icc (O/V2) <u>7/</u>	$\begin{split} t_\text{w} &\geq 100~\mu\text{s}, t_\text{cool} \geq t_\text{w} \\ 5~\mu\text{s} &\leq t_\text{r} \leq 5~\text{ms} \\ 5~\mu\text{s} &\leq t_\text{f} \leq 5~\text{ms} \\ V_\text{test} &= 6.0~\text{V} \\ V_\text{CCQ} &= 5.5~\text{V} \\ V_\text{over} &= 9.0~\text{V} \end{split}$	AII Q, V	5.5 V	2		100	mA
Functional test 3014	<u>8</u> /	$V_{IN} = V_{IL}$ or V_{IH} Verify output V_{OUT} See 4.4.1d	AII AII	3.0 V	7, 8	L	Н	
				4.5 V	7, 8	L	Н	
Propagation delay time, data to odd	t _{PLH1,} t _{PHL1}	$C_L = 50 \text{ pF minimum}$ $R_L = 500\Omega$	All Q, V	3 0 V	9, 11 10	1.0	17.0 20.0	ns
parity output, In to ΣO	<u>9</u> /	See figure 4	All M		9 10, 11	1.0 1.0	17.0 20.0	ns
3003			All Q, V	4.5 V	9, 11 10 9	1.0	13.0 14.5	ns
			All M		10, 11	1.0	13.0 14.5	ns
Propagation delay time, data to even	t _{PLH2,} t _{PHL2}	$C_L = 50 \text{ pF minimum}$ $R_L = 500\Omega$	All Q, V	3 0 V	9, 11 10	1.0 1.0	17.0 20.0	ns
parity output, In to ΣE	<u>9</u> /	See figure 4	All M		9 10, 11	1.0	17.0 20.0	ns
3003			All Q, V	4.5 V	9, 11 10	1.0	13.0 14.5	ns
			All M		9	1.0	13.0 14.5	ns

- 1/ For tests not listed in the referenced MIL-STD-883 [e.g. I_{CC} (O/V1)], utilize the general test procedure of 883 under the conditions listed herein. All inputs and outputs shall be tested, as applicable, to the tests in table I herein.
- 2/ Each input/output, as applicable shall be tested at the specified temperature for the specified limits. Output terminals not designated shall be high level logic, low level logic, or open, except as follows:
 - a. V_{IC} (pos) tests, the GND terminal can be open. $T_C = +25^{\circ}C$.
 - b. V_{IC} (neg) tests, the V_{CC} terminal shall be open. T_C = +25°C.
 - c. For all I_{CC} tests, the output terminal shall be open. When performing these tests, the current meter shall be placed in the circuit such that all current flows through the meter.

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TABLE I. Electrical performance characteristics - Continued.

- 3/ The word "All" in the device type and device class column, means limits for all device types and classes.
- 4/ For negative and positive voltage and current values, the sign designates the potential difference in reference to GND and the direction of current flow, respectively; and the absolute value of the magnitude, not the sign, is relative to the minimum and maximum limits, as applicable, listed herein.
- 5/ Transmission driving tests are performed at $V_{CC} = 5.5 \text{ V}$ with a 2 ms duration maximum. This test may be performed using $V_{IN} = V_{CC}$ or GND. When $V_{IN} = V_{CC}$ or GND is used, the test is guaranteed for $V_{IN} = V_{IH}$ or V_{IL} .
- 6/ Power dissipation capacitance (C_{PD}) determines both the power consumption (P_D) and current consumption (I_S). where:

$$\begin{split} P_D &= (C_{PD} + C_L) \ (V_{CC} \ x \ V_{CC}) \ f + (I_{CC} \ x \ V_{CC}). \\ I_S &= (C_{PD} + C_L) \ V_{CC} f + I_{CC}. \end{split}$$

f is the frequency of the input signal; C_L is the external output load capacitance.

- Yover are to be accurate within ±5 percent.
 See EIA/JEDEC STD. No. 78 for electrically induced latch-up test methods and procedures. The values listed for Itrigger and Vover are to be accurate within ±5 percent.
- 8/ Tests shall be performed in sequence, attributes data only. Functional tests shall include the truth table and other logic patterns used for fault detection. The test vectors used to verify the truth table shall, at a minimum, test all functions of each input and output. All possible input to output logic patterns per function shall be guaranteed, if not tested, to the truth table in figure 2 herein. Functional tests shall be performed in sequence as approved by the qualifying activity on qualified devices. Allowable tolerances per MIL-STD-883 for the input voltage levels may be incorporated. For outputs, L < 0.3V_{CC} and H ≥ 0.7V_{CC}.
- 9/ AC limits at $V_{CC} = 5.5$ V are equal to the limits at $V_{CC} = 4.5$ V and guaranteed by testing at $V_{CC} = 4.5$ V. AC limits at $V_{CC} = 3.6$ V are equal to the limits at $V_{CC} = 3.0$ V and guaranteed by testing at $V_{CC} = 3.0$ V. Minimum propagation delay limits for $V_{CC} = 5.5$ V and $V_{CC} = 3.6$ V are 1.0 ns and guaranteed by guardbanding the $V_{CC} = 4.5$ V and $V_{CC} = 3.0$ V, respectively, minimum limits to 1.5 ns. For propagation delay tests, all paths must be tested.

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Device types	Al	I
Case Outlines	C, D, X	2
Terminal Number	Terminal	Terminal
Terminal Number	Symbol	Symbol
1	16	NC
2	17	16
3	NC	17
4	18	NC
5	ΣE	NC
6	ΣΟ	18
7	GND	NC
8	10	ΣE
9	I 1	ΣΟ
10	12	GND
11	13	NC
12	14	10
13	15	I1
14	V_{CC}	12
15		NC
16		13
17		NC
18		14
19		15
20		V_{CC}

NC = No internal connection

Pin description			
Terminal symbol	Description		
In (n = 0 to 8)	Data inputs		
ΣΟ	Odd parity output		
ΣΕ	Even parity output		

FIGURE 1. Terminal connections.

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Inputs	Outputs		
Number of HIGH	ΣΕ	ΣΟ	
inputs I0 to I8			
0, 2, 4, 6, 8	Н	L	
1, 3, 5, 7, 9	L	Н	

H = High voltage level.L = Low voltage level.

FIGURE 2. Truth table.

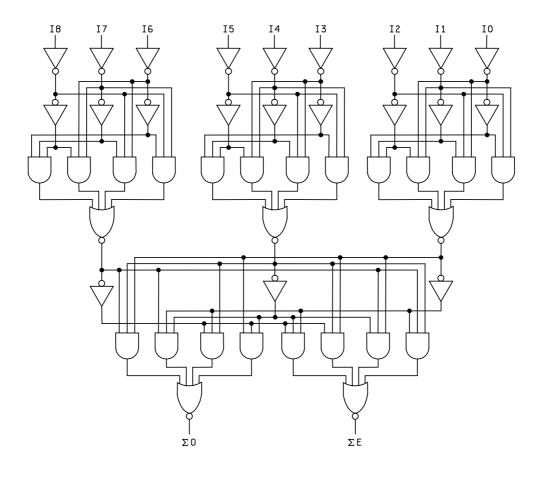
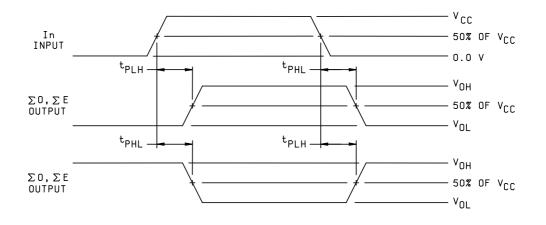
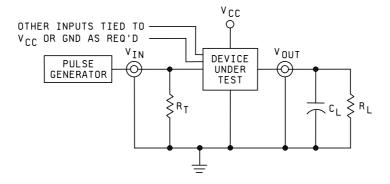


FIGURE 3. Logic diagram.

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NOTES:

- 1. $C_L = 50$ pF minimum or equivalent (includes jig and probe capacitance).
- 2. $R_L = 500\Omega$ or equivalent.
- 3. $R_T = 50\Omega$ or equivalent.
- 4. Input signal from pulse generator: V_{IN} = 0.0 V to V_{CC} ; PRR \leq 10 MHz; $t_r \leq$ 3.0 ns, $t_f \leq$ 3.0 ns; t_r and t_f shall be measured from 10% to 90% of V_{CC} and 90% to 10% of V_{CC} , respectively.
- 5. Timing parameters shall be tested at a minimum input frequency of 1 MHz.
- 6. The outputs are measured one at a time with one transition per measurement.

FIGURE 4. Switching waveforms and test circuit.

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4. VERIFICATION

- 4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C or D. Test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015.
 - (2) $T_A = +125^{\circ}C$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein.

TABLE II. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	(in acco	ogroups ordance with 38535, table III)
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)			1
Final electrical parameters (see 4.2)	<u>1</u> / 1, 2, 3, 7, 8, 9, 10, 11	<u>1</u> / 1, 2, 3, 7, 8, 9, 10, 11	<u>2</u> / <u>3</u> / 1, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (see 4.4)	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	<u>3</u> / 1, 2, 3, 7,8, 9, 10, 11
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9	1, 7, 9

1/ PDA applies to subgroup 1. 2/ PDA applies to subgroups 1, 7, and deltas.

^{3/} Delta limits, as specified in table III, shall be required where specified, and the delta limits shall be completed with reference to the zero hour electrical parameters.

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TABLE III. Burn-in and operating life test delta parameters (+25°C).

Parameter 1/	Symbol	Device types	Delta Limits
Supply current	I _{CCH} , I _{CCL}	01	±100 nA <u>2</u> /
		02	±300 nA
Supply current delta	ΔI_{CC}	02	±0.4 mA
Input current low level	I _{IL}	02	±20 nA
Input current high level	I _{IH}	02	±20 nA
Output voltage low level	V _{OL}	02	±0.04 V
$(V_{CC} = 5.5 \text{ V}, I_{OL} = 24 \text{ mA})$			
Output voltage high level	V _{OH}	02	±0.20 V
$(V_{CC} = 5.5 \text{ V}, I_{OH} = -24 \text{ mA})$			

- 1/ These parameters shall be recorded before and after the required burn-in and life tests to determine delta limits.
- 2/ The limit may not be production tested.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.
- 4.3 <u>Qualification inspection for device classes Q and V.</u> Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
- 4.4 <u>Conformance inspection</u>. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Latch-up tests are required for device classes Q and V. These tests shall be performed only for initial qualification and after process or design changes that may affect the performance of the device. Latch-up tests shall be considered destructive. For latch-up tests, test all applicable pins on five devices with zero failures.
- c. C_{IN} and C_{PD} shall be measured only for initial qualification and after process or design changes which may affect capacitance. C_{IN} shall be measured between the designated terminal and GND at a frequency of 1 MHz. C_{PD} shall be tested in accordance with the latest revision of JEDEC Standard No. 20 and table I herein. For C_{IN} and C_{PD}, test all applicable pins on five devices with zero failures.

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- d. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table in figure 2 herein. The test vectors used to verify the truth table shall, at a minimum, test all functions of each input and output. All possible input to output logic patterns per function shall be guaranteed, if not tested, to the truth table in figure 2, herein. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.
- 4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.
- 4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:
 - a Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - b. $T_A = +125^{\circ}C$, minimum.
 - c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- 4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - 4.4.3 Group D inspection. Group D inspection end-point electrical parameters shall be as specified in table II herein.
- 4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as specified in table I at $T_A = +25$ °C, after exposure, to the subgroups specified in table II herein.
 - 4.5 Methods of inspection. Methods of inspection shall be specified as follows:
- 4.5.1 <u>Voltage and current</u>. Unless otherwise specified, all voltages given are referenced to the microcircuit GND terminal. Currents given are conventional current and positive when flowing into the referenced terminal.
 - 5. PACKAGING
- 5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

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6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
 - 6.1.2 Substitutability. Device class Q devices will replace device class M devices.
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.
- 6.3 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.
- 6.4 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.
- 6.5 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.
 - 6.6 Sources of supply.
- 6.6.1 <u>Sources of supply for device classes Q and V</u>. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.
- 6.6.2 <u>Approved sources of supply for device class M.</u> Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN DATE: 10-04-01

Approved sources of supply for SMD 5962-92201 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-9220101MCA	0C7V7	54AC280DMQB
5962-9220101MDA	0C7V7	54AC280FMQB
5962-9220101M2A	0C7V7	54AC280LMQB
5962-9220102QXA	<u>3</u> /	54AC280K02Q
5962-9220102QXC	<u>3</u> /	54AC280K01Q
5962-9220102VXA	<u>3</u> /	54AC280K02V
5962-9220102VXC	<u>3</u> /	54AC280K01V

- The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the Vendor to determine its availability.
- <u>2</u>/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply.

Vendor CAGEVendor namenumberand address

0C7V7 QP Semiconductor

2945 Oakmead Village Court Santa Clara, CA 95051

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